PROCEEDINGS OF SPIE

Semiconductor Lasers and Applications XI

Wei Li Werner H. Hofmann Yikai Su Editors

10–12 October 2021 Nantong, China

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Published by SPIE

Volume 11891

Proceedings of SPIE 0277-786X, V. 11891

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Please use the following format to cite material from these proceedings: Author(s), "Title of Paper," in *Semiconductor Lasers and Applications XI*, edited by Wei Li, Werner H. Hofmann, Yikai Su, Proc. of SPIE 11891, Seven-digit Article CID Number (DD/MM/YYYY); (DOI URL).

ISSN: 0277-786X ISSN: 1996-756X (electronic)

ISBN: 9781510646315 ISBN: 9781510646322 (electronic)

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